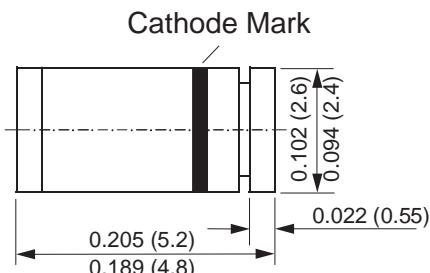
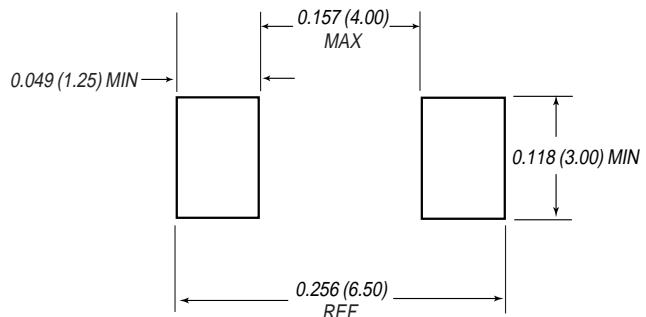


Zener Diodes


Glass MELF

Dimensions in inches and (millimeters)
Mounting Pad Layout


Mechanical Data

Case: MELF Glass Case

Weight: approx. 0.25g

Packaging Codes/Options:

 E4/K per 13" reel (12mm tape), 10K/box
 25/1.5K per 7" reel (12mm tape), 12K/box

Features

- Silicon Planar Power Zener Diodes
- For use in stabilizing and clipping circuits with higher power rating.
- The Zener voltages are graded according to the international E 24 standard. Smaller voltage tolerances are available upon request.
- These diodes are also available in the DO-41 case with the type designation ZPY1 ... ZPY100.

Maximum Ratings and Thermal Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Parameter	Symbol	Value	Unit
Zener Current (see Table "Characteristics")			
Power Dissipation at T _{amb} = 25°C	P _{tot}	1.0 ⁽¹⁾	W
Thermal Resistance Junction to Ambient (Max.)	R _{θJA}	170 ⁽¹⁾	°C/W
Thermal Resistance Junction to Case (Typ.)	R _{θJC}	60	°C/W
Junction Temperature	T _j	175	°C
Storage Temperature Range	T _s	-55 to +175	°C

Note:

(1) Valid provided that electrodes are kept at ambient temperature.

ZMY1 thru ZMY100

Vishay Semiconductors
formerly General Semiconductor



Electrical Characteristics

Ratings at 25°C ambient temperature unless otherwise specified.

Type	Zener Voltage ⁽²⁾ at I _{ZT} V _Z (V)		Dynamic Resistance at I _{ZT} f = 1 kHz r _Z (Ω)	Temp. Coeff. of Zener Voltage at I _{ZT} α _{VZ} (10 ⁻⁴ /°C)		Test current I _{ZT} (mA)	Reverse Voltage at I _R = 0.5 μA V _R (V)	Admissible Zener current ⁽¹⁾ at T _{amb} = 25°C I _Z (mA)
	min.	max.		min.	max.			
ZMY1 ⁽³⁾	0.65	0.75	6.5 (< 8)	-26	-23	5	-	406
ZMY3.9	3.7	4.1	4 (< 7)	-7	+2	100	-	203
ZMY4.3	4.0	4.6	4 (< 7)	-7	+3	100	-	182
ZMY4.7	4.4	5.0	4 (< 7)	-7	+4	100	-	165
ZMY5.1	4.8	5.4	2 (< 5)	-6	+5	100	> 0.7	150
ZMY5.6	5.2	6.0	1 (< 2)	-3	+5	100	> 1.5	135
ZMY6.2	5.8	6.6	1 (< 2)	-1	+6	100	> 2.0	128
ZMY6.8	6.4	7.2	1 (< 2)	0	+7	100	> 3.0	110
ZMY7.5	7.0	7.9	1 (< 2)	0	+7	100	> 5.0	100
ZMY8.2	7.7	8.7	1 (< 2)	+3	+8	100	> 6.0	89
ZMY9.1	8.5	9.6	2 (< 4)	+3	+8	50	> 7.0	82
ZMY10	9.4	10.6	2 (< 4)	+5	+9	50	> 7.5	74
ZMY11	10.4	11.6	3 (< 7)	+5	10	50	> 8.5	66
ZMY12	11.4	12.7	3 (< 7)	+5	+10	50	> 9.0	60
ZMY13	12.4	14.1	4 (< 9)	+5	+10	50	> 10	55
ZMY15	13.8	15.8	4 (< 9)	+5	+10	50	> 11	49
ZMY16	15.3	17.1	5 (< 10)	+7	+11	25	> 12	44
ZMY18	16.8	19.1	5 (< 11)	+7	+11	25	> 14	40
ZMY20	18.8	21.2	6 (< 12)	+7	+11	25	> 15	36
ZMY22	20.8	23.3	7 (< 13)	+7	+11	25	> 17	34
ZMY24	22.8	25.6	8 (< 14)	+7	+12	25	> 18	29
ZMY27	25.1	28.9	9 (< 15)	+7	+12	25	> 20	27
ZMY30	28	32	10 (< 20)	+7	+12	25	> 22.5	25
ZMY33	31	35	11 (< 20)	+7	+12	25	> 25	22
ZMY36	34	38	25 (< 60)	+7	+12	10	> 27	20
ZMY39	37	41	30 (< 60)	+8	+12	10	> 29	18
ZMY43	40	46	35 (< 80)	+8	+13	10	> 32	17
ZMY47	44	50	40 (< 80)	+8	+13	10	> 35	15
ZMY51	48	54	45 (< 100)	+8	+13	10	> 38	14
ZMY56	52	60	50 (< 100)	+8	+13	10	> 42	13
ZMY62	58	66	60 (< 130)	+8	+13	10	> 47	11
ZMY68	64	72	65 (< 130)	+8	+13	10	> 51	10
ZMY75	70	79	70 (< 160)	+8	+13	10	> 56	9
ZMY82	77	88	80 (< 160)	+8	+13	10	> 61	8
ZMY91	85	96	120 (< 250)	+9	+13	5	> 68	7.5
ZMY100	94	106	130 (< 250)	+9	+13	5	> 75	7

Notes: (1) Valid provided that electrodes are kept at ambient temperature

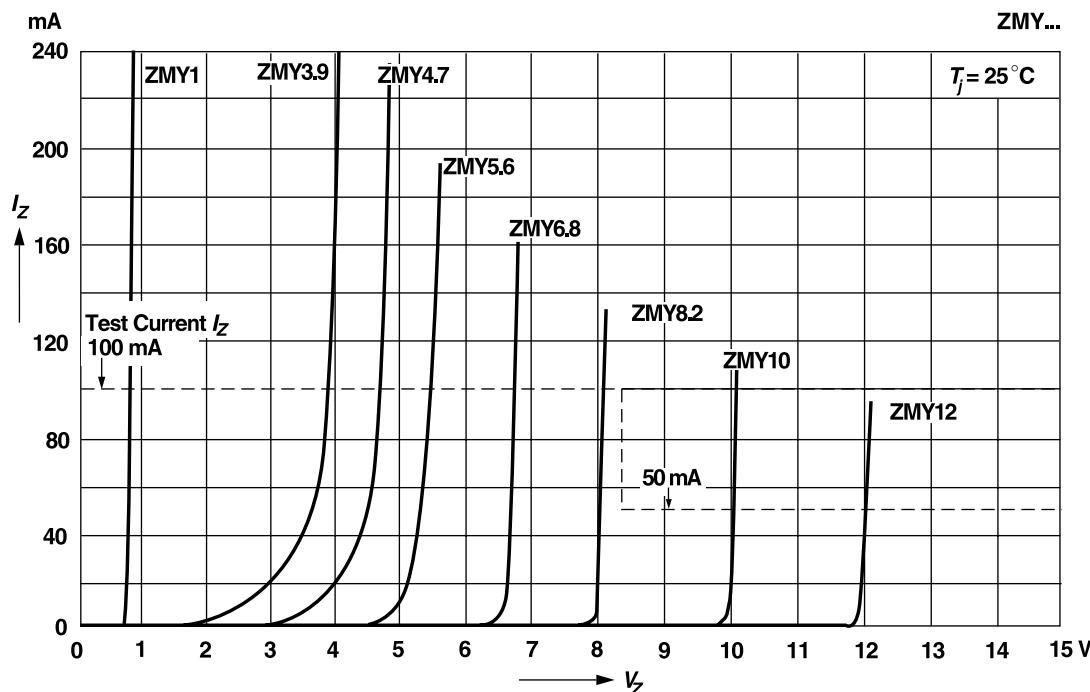
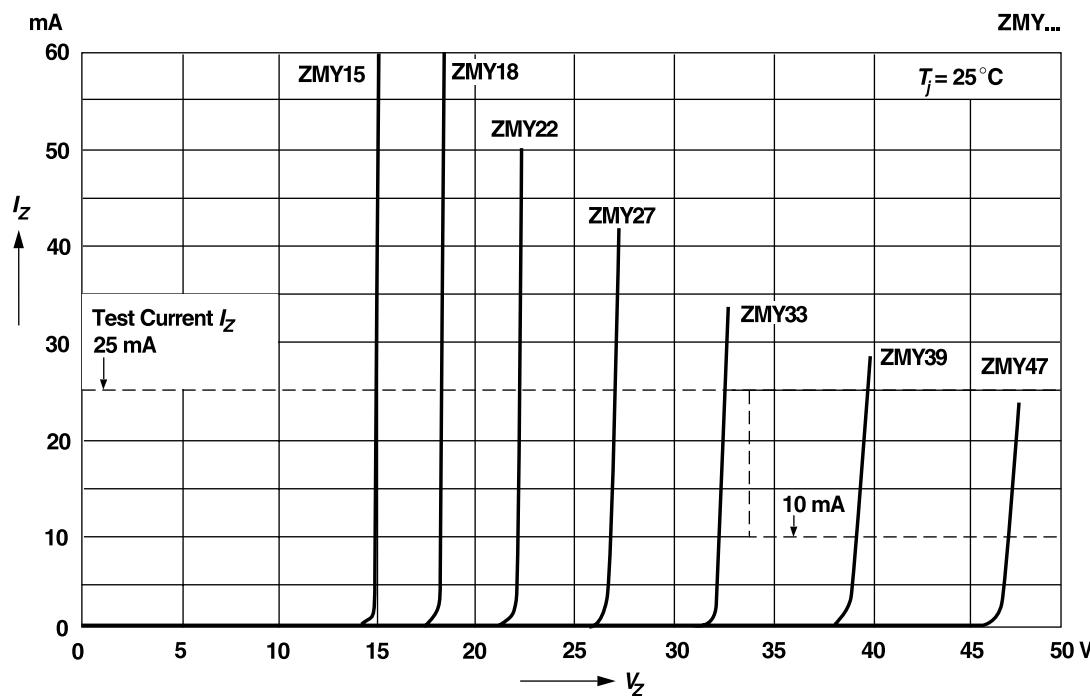
(2) Tested with pulses t_p = 5ms

(3) The ZMY1 is a silicon diode operated in forward direction. Hence, the index of all characteristics and maximum ratings should be "F" instead of "Z".

Connect the cathode terminal to the negative pole

For devices in glass case MELF with higher Zener voltage but same power dissipation see types ZMU100 ... ZMU180

**Ratings and
Characteristic Curves** ($T_A = 25^\circ\text{C}$ unless otherwise noted)

Breakdown characteristics
 $T_j = \text{constant (pulsed)}$

Breakdown characteristics
 $T_j = \text{constant (pulsed)}$


ZMY1 thru ZMY100

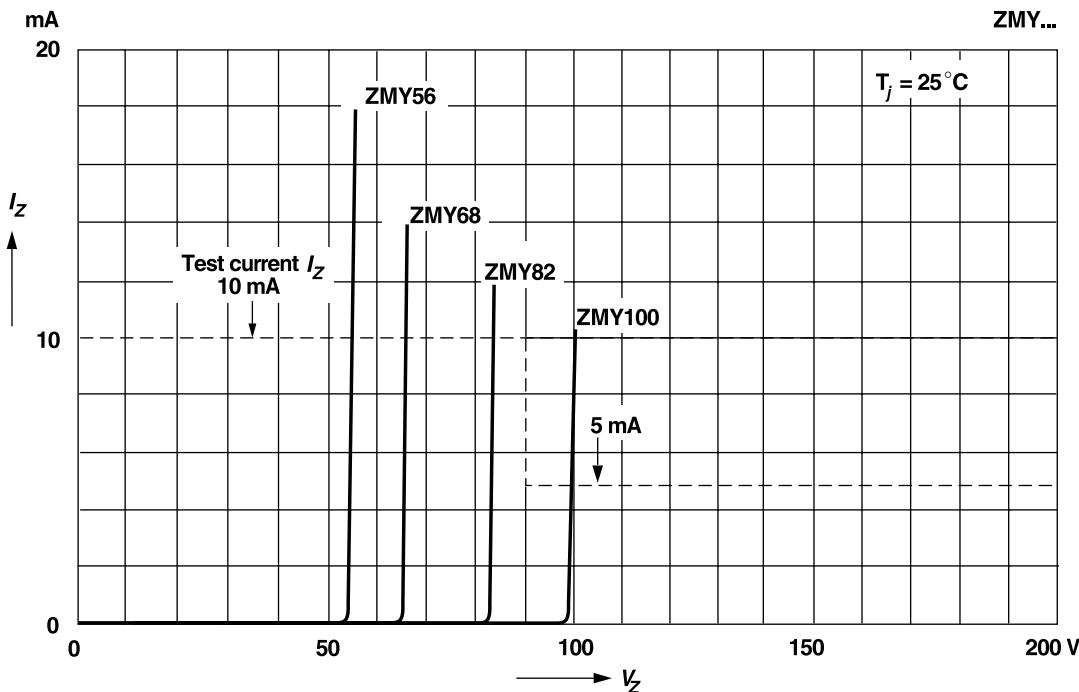


Vishay Semiconductors
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Ratings and Characteristic Curves ($T_A = 25^\circ\text{C}$ unless otherwise noted)

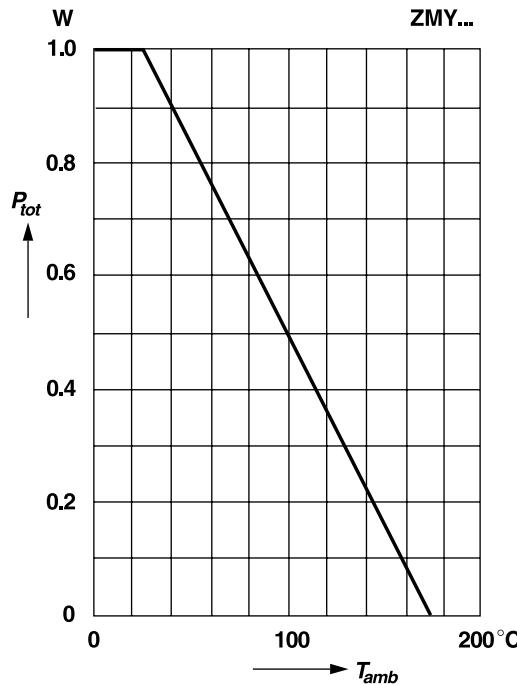
Breakdown characteristics

$T_j = \text{constant (pulsed)}$



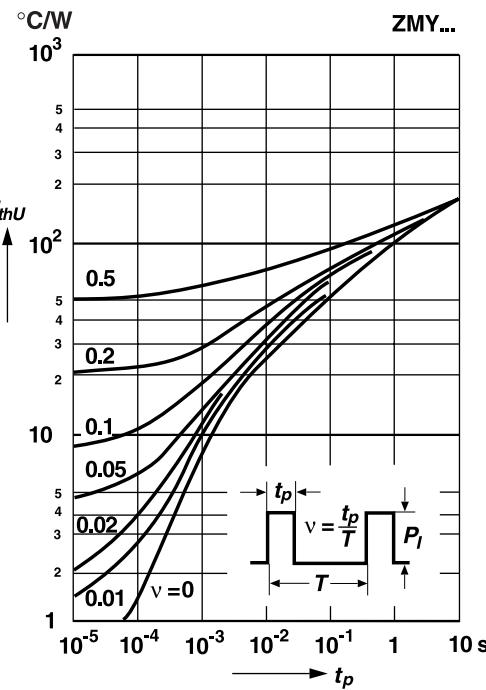
Admissible power dissipation versus ambient temperature

Valid provided that electrodes are kept at ambient temperature

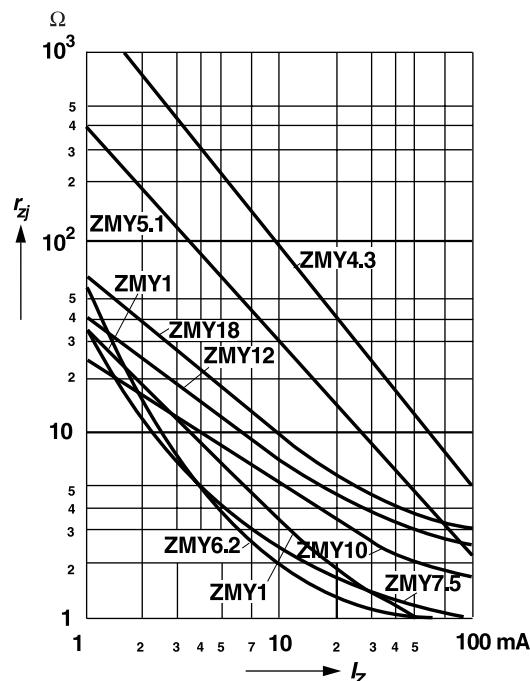


Pulse thermal resistance versus pulse duration

Valid provided that electrodes are kept at ambient temperature



**Ratings and
Characteristic Curves** ($T_A = 25^\circ\text{C}$ unless otherwise noted)

 Dynamic resistance
 versus Zener current

 Dynamic resistance
 versus Zener current

 Dynamic resistance
 versus Zener current
